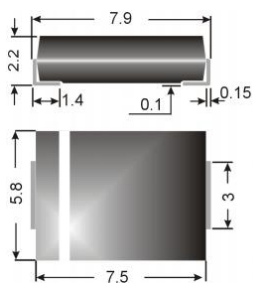


S3A ... S3M



Surface mount diode

Standard silicon rectifier diodes

S3A...S3M

Forward Current: 3 A

Reverse Voltage: 50 to 1000 V

Features

- Max. solder temperature: 260°C
- Plastic material has UL classification 94V-0

Mechanical Data

- Plastic case: SMC / DO 214AB
- Weight approx.: 0,21 g
- Terminals: plated terminals solderable per MIL-STD-750
- Mounting position: any
- Standard packaging: 3000 pieces per reel

1) Max. temperature of the terminals $T_T = 100^\circ\text{C}$

2) $I_F = 3\text{ A}$, $T_j = 25^\circ\text{C}$

3) $T_A = 25^\circ\text{C}$

4) Mounted on P.C. board with 60 mm² copper pads at each terminal

Type	Polarity color band	Repetitive peak reverse voltage V_{RRM} V	Surge peak reverse voltage V_{RSM} V	Maximum forward voltage $T_j = 25^\circ\text{C}$ $I_F = 3\text{ A}$ $V_F^{(2)}$ V	Maximum reverse recovery time $I_F = -\text{A}$ $I_R = -\text{A}$ $I_{RR} = -\text{A}$ t_{rr} ns
S3A	-	50	50	1,15	-
S3B	-	100	100	1,15	-
S3D	-	200	200	1,15	-
S3G	-	400	400	1,15	-
S3J	-	600	600	1,15	-
S3K	-	800	800	1,15	-
S3M	-	1000	1000	1,15	-

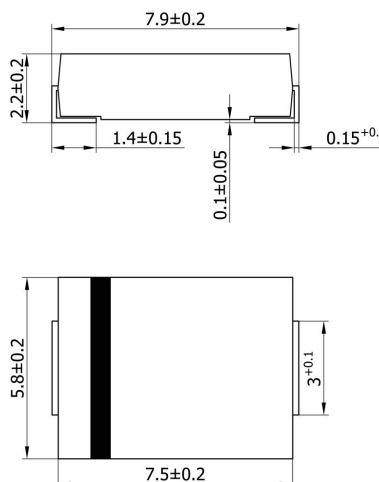
Absolute Maximum Ratings $T_c = 25^\circ\text{C}$, unless otherwise specified

Symbol	Conditions	Values	Units
I_{FAV}	Max. averaged fwd. current, R-load, $T_T = 100^\circ\text{C}$	3	A
I_{FRM}	Repetitive peak forward current $f > 15\text{ Hz}^1)$	20	A
I_{FSM}	Peak fwd. surge current 50 Hz half sinus-wave ³⁾	100	A
I^2t	Rating for fusing, $t < 10\text{ ms}^3)$	50	A ² s
R_{thA}	Max. thermal resistance junction to ambient ⁴⁾	50	K/W
R_{thT}	Max. thermal resistance junction to terminals	10	K/W
T_j	Operating junction temperature	-50...+150	°C
T_s	Storage temperature	-50...+150	°C

Characteristics $T_c = 25^\circ\text{C}$, unless otherwise specified

Symbol	Conditions	Values	Units
I_R	Maximum leakage current, $T_j = 25^\circ\text{C}$; $V_R = V_{RRM}$	<5	µA
	$T_j = 100^\circ\text{C}$; $V_R = V_{RRM}$	<200	µA
C_j	Typical junction capacitance (at MHz and applied reverse voltage of V)	-	pF
Q_{rr}	Reverse recovery charge ($U_R = V$; $I_F = A$; $dI_F/dt = A/ms$)	-	µC
E_{RSM}	Non repetitive peak reverse avalanche energy ($I_R = mA$; $T_j = ^\circ\text{C}$; inductive load switched off)	-	mJ

Dimensions in mm



case: SMC / DO214AB

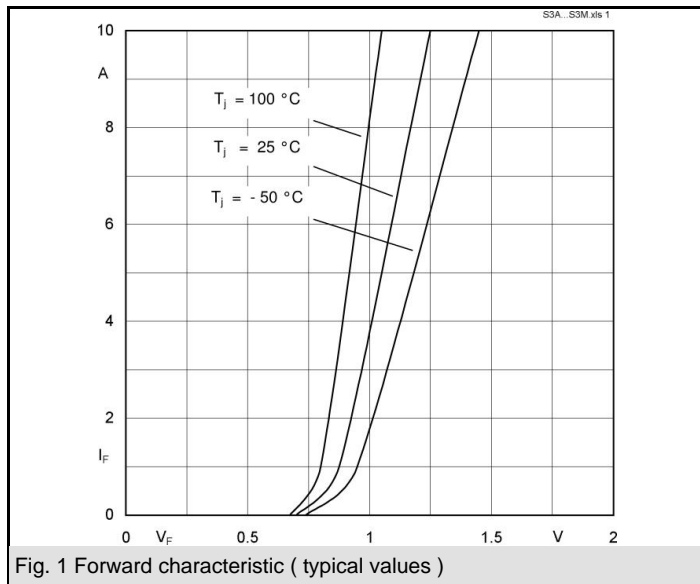


Fig. 1 Forward characteristic (typical values)

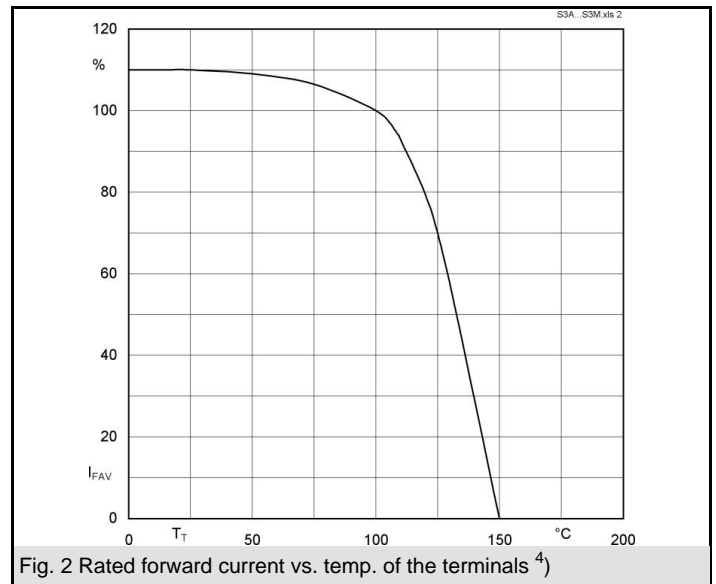


Fig. 2 Rated forward current vs. temp. of the terminals ⁴⁾